

Supplementary Materials

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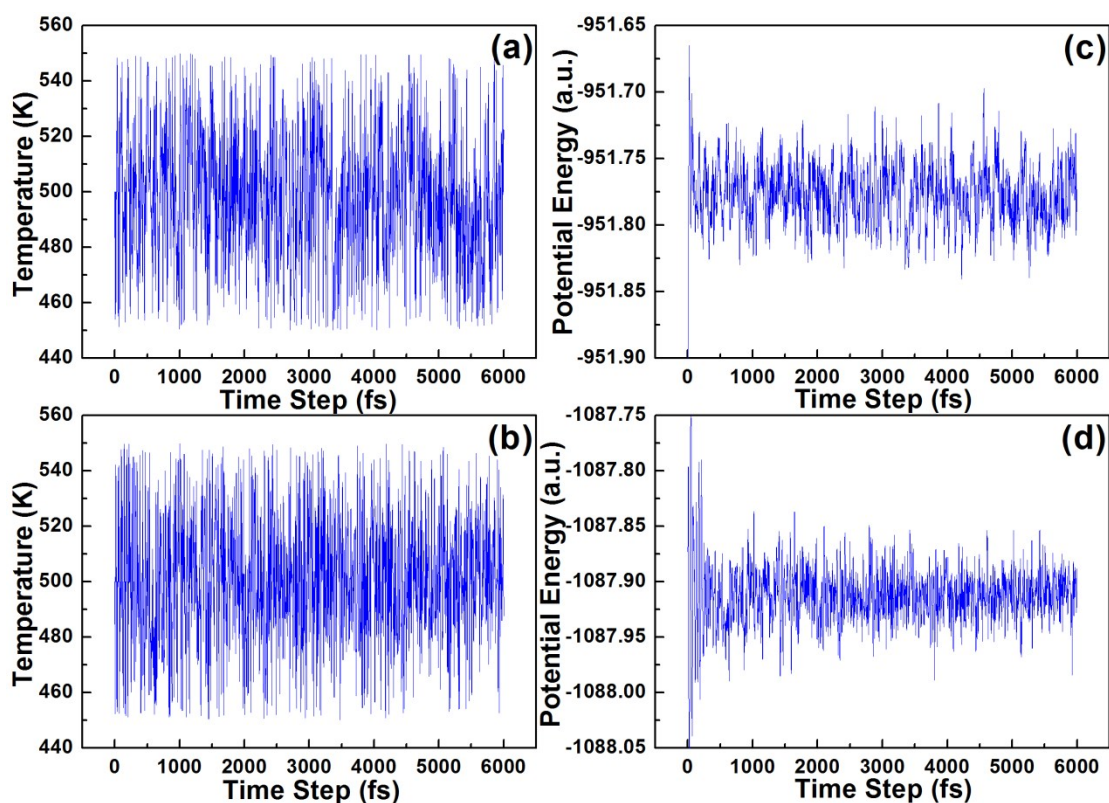
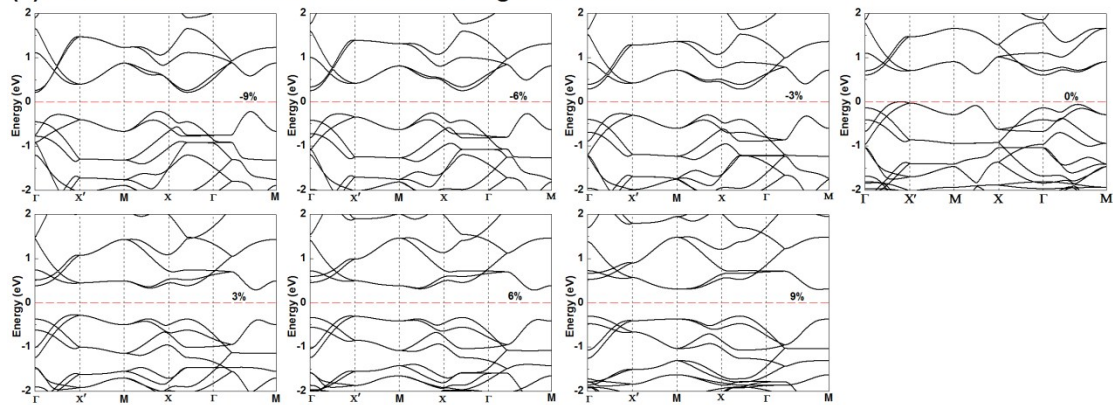


Fig. S1 (a) and (b) are the temperature of C_y and C_z in function of time steps, respectively. (c) and (d) are the total energy of C_y and C_z in function of time steps, respectively. All data were obtained by performing ab initio molecular dynamics simulations.

(a) band structure with strain for C_z along lattice vector a



(b) band structure with strain for C_z along lattice vector c

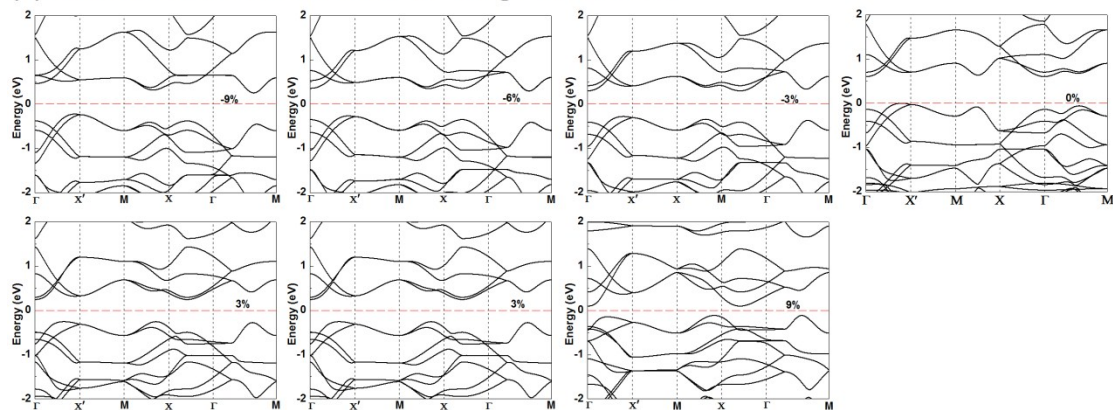


Fig. S2: (a) and (b) show the band gap as a function of strain for C_y and C_z .